# 4:1 High-Speed USB Multiplexer/Switch



#### Description

The FSUSB74 is a Bi-directional, Low-Power, High-Speed USB 2.0 4:1 MUX. It is Optimized for Switching from four High-Speed (480Mbps) sources or any combination of High-Speed and full-/low-speed USB/UART sources to one USB 2.0 connector.

#### Applications

- MP3 Portable Media Players
- Cellular Phones, Smart Phones
- Netbooks, Mobile Internet Devices (MID)

#### **Related Resources**

- FSUSB74 Demonstration Board
- FSUSB74 Evaluation Board

#### Features

Switch Type	4:1
USB	USB 2.0 High–Speed Compliant USB 2.0 Full–Speed Compliant
R <sub>ON</sub>	6.5 Ω
C <sub>ON</sub>	7.5 pF
ESD (IEC61000-4-2)	15 kV (Air) 8 kV (Contact)
V <sub>CC</sub>	2.7 to 4.4 V
I <sub>CCSLP</sub>	<1 µA
ICCACT	9 μΑ
Package	16– Lead UMLP 1.80 x 2.60 x 0.55mm, 0.40mm Pitch 16–Lead MLP 3 x 3 x 0.7mm, 0.5mm Pitch
Ordering Information	FSUSB74UMX (UMLP) FSUSB74MPX (MLP)





WQFN 16 3X3, 0.5P CASE 510BS

UQFN 16 1.8X2.6, 0.6P CASE 523BF

#### MARKING DIAGRAM



LC,FSUSB74 = Device Code

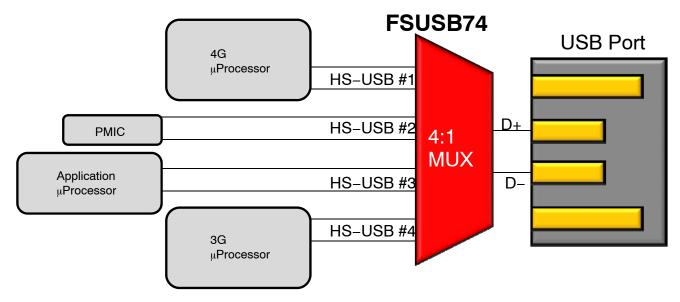
- &Z = Assembly Plant Code
- &2 = 2-Digit Date Code
- &K = 2-Digits Lot Run Lot Traceability Code FSUSB74 = Specific Device Code

#### **ORDERING INFORMATION**

Device	Package	Shipping <sup>†</sup>
FSUSB74MPX	WQFN–16 (Pb–Free)	3000 / Tape & Reel
FSUSB74UMX	UQFN–16 (Pb–Free)	3000 / Tape & Reel

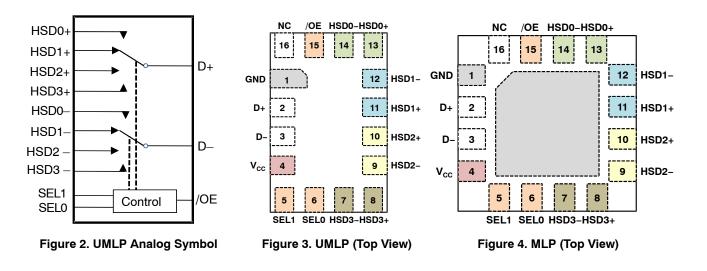
†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, <u>BRD8011/D</u>.

# TYPICAL APPLICATION





# **PIN CONFIGURATIONS**



#### **PIN DESCRIPTIONS**

Pin No.	Name	Туре	Description
1	GND	Ground	Ground
2	D+	I/O	D+ common port (HS or FS USB)
3	D-	I/O	D– common port (HS or FS USB)
4	V <sub>CC</sub>	Power Supply	Supply Voltage
5	SEL1	Input	Path Selection Control Input (see truth table below)
6	SEL0	Input	Path Selection Control Input (see truth table below)
7	HSD3-	I/O	D- from fourth source path (HS or FS USB)
8	HSD3+	I/O	D+ from fourth source path (HS or FS USB)
9	HSD2-	I/O	D- from third source path (HS or FS USB)
10	HSD2+	I/O	D+ from third source path (HS or FS USB)
11	HSD1+	I/O	D+ from second source path (HS or FS USB)
12	HSD1-	I/O	D- from second source path (HS or FS USB)
13	HSD0+	I/O	D+ from first source path (HS or FS USB)
14	HSD0-	I/O	D- from first source path (HS or FS USB)
15	/OE	Input	D- from first source path (HS or FS USB)
16	NC	-	No Connect

# TRUTH TABLE

/OE	SEL1	SEL0	Function			
1	х	Х	D+, D- Switch Paths Open			
0	0	0	D+ = HSD0 +, D- = HSD0-			
0	0	1	D+ = HSD1+, D- = HSD1-			
0	1	0	D+ = HSD2+, D- = HSD2-			
0	1	1	D+ = HSD3+, D- = HSD3-			

#### **ABSOLUTE MAXIMUM RATINGS**

Symbol	Parameter			Max.	Unit
V <sub>CC</sub>	Supply Voltage		-0.5	5.25	V
V <sub>CNTRL</sub>	DC Input Voltage (SEL1, SEL0, /OE, SELS) <sup>(1)</sup>		-0.50	V <sub>CC</sub>	V
V <sub>SW</sub>	DC Switch I/O Voltage <sup>(1)</sup>		-0.50	5.25	V
I <sub>IK</sub>	DC Input Diode Current		-50	_	mA
T <sub>STG</sub>	Storage Temperature			+150	°C
MSL	Moisture Sensitivity Level (JEDEC J-STD-020A)		-	1	Level
ESD	IEC61000-4-2 System on USB connector pins D+ & D-	Air Gap	15	_	kV
		Contact	8	_	
	Human Body Model, JEDEC: JESD22-A114	D+,D- to GND	6	-	
		Power to GND	12	_	
		All Other Pins	2	_	

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected. 1. The input and output negative ratings may be exceeded if the input and output diode current ratings are observed.

#### **RECOMMENDED OPERATING CONDITIONS**

Symbol	Parameter	Min.	Max.	Unit
V <sub>CC</sub>	Supply Voltage	2.5	4.4	V
V <sub>CNTRL</sub> (Note 2)	Control Input Voltage (SEL1, SEL0, /OE, and SELS)	0	V <sub>CC</sub>	V
V <sub>SW</sub>	Switch I/O Voltage	-0.5	4.4	V
T <sub>A</sub>	Operating Temperature	-40	+85	°C

Functional operation above the stresses listed in the Recommended Operating Ranges is not implied. Extended exposure to stresses beyond the Recommended Operating Ranges limits may affect device reliability.

2. The control input must be held HIGH or LOW; it must not float.

#### DC ELECTRICAL CHARACTERISTICS (All typical values are for V<sub>CC</sub> = 3.3 V at 25°C unless otherwise specified.)

				$T_A = -40^{\circ}C$ to $85^{\circ}C$		85°C	
Symbol	Parameter	Test Conditions	V <sub>CC</sub> (V)	Min.	Тур.	Max.	Unit
R <sub>ON</sub> <sup>(Note 3)</sup>	HS Switch On Resistance	$V_{SW}$ = 0.4 V, $I_{ON}$ = -8 mA, Figure 5	3.3		6.5	9.0	Ω
$\Delta R_{ON}^{(Note 3)}$	HS Delta Ron (Note 4)	$V_{SW} = 0.4 \text{ V}, I_{ON} = -8 \text{ mA}$	3.3		0.5	0.5	Ω
I <sub>IN</sub>	Control Input Leakage	All Combinations of /OE,SEL1 & SEL0 in the Truth Table $(1 = V_{CC}, 0 = 0 V)$	4.4	-1	-	-	μΑ
I <sub>OZ</sub>	Off State Leakage	$0 \le Dn$ , HSD0n, HSD1n, HSD2n, HSD3n $\le 4.4 \text{ V}$	4.4	-1	-	_	μΑ
I <sub>OFF</sub>	Power-Off Leakage Current (All I/O Ports)	$V_{SW}$ = 0 V to 4.4 V, $V_{CC}$ = 0 V, Figure 6	0	-1	-	-	μΑ
I <sub>CCSLP</sub>	Sleep Mode Supply Current	/OE = V <sub>CC</sub>	4.4	-	-	-	μA
ICCACT	Active Mode Supply Current	All Active Modes in Truth Table	4.4	-	9	18	μA
I <sub>CCT</sub>	Increase in I <sub>CC</sub> Current per	V <sub>CNTRL</sub> = 1.8 V	4.4	-	3.3	4.0	μA
	Control Input and V <sub>CC</sub>	V <sub>CNTRL</sub> = 1.2 V	4.4	-	4.9	6.0	μA
V <sub>IK</sub>	Clamp Diode Voltage	I <sub>IN</sub> = -18 mA	2.5	-	-	-1.2	V
V <sub>IH</sub>	Control Input Voltage High	SEL1, SEL0, /OE	2.5 to 4.4	1.0	-	-	V
VIL	Control Input Voltage Low	SEL1, SEL0, /OE	2.5 to 4.4	-	_	0.35	V

3. Measured by the voltage drop between HSDn and Dn pins at the indicated current through the switch. On resistance is determined by the lower of the voltage on the two (HSDn or Dn ports).

4. Guaranteed by characterization.

#### AC ELECTRICAL CHARACTERISTICS (All typical values are for V<sub>CC</sub> = 3.3 V at T<sub>A</sub> = $25^{\circ}$ C unless otherwise specified.)

				T <sub>A</sub> =	–40°C to	85°C	
Symbol	Parameter	Test Conditions	V <sub>CC</sub> (V)	Min.	Тур.	Max.	Unit
ton	Turn-On Time when Switching from One USB Path (or Disabled i.e. /OE=1) to Another USB Path	$R_{L}$ = 50 $\Omega$ , $C_{L}$ = 35 pF, $V_{SW}$ = 0.8 V, Figure 7, Figure 8	2.5 to 4.4	126	-	400	μs
t <sub>OFF</sub>	Turn–Off Time, Turning Off Any of the USB Paths	$R_{L}$ = 50 $\Omega,$ $C_{L}$ = 35 pF, $V_{SW}$ = 0.8 V, Figure 7, Figure 8	2.5 to 4.4	-	-	80	ns
t <sub>PD</sub>	Propagation Delay (Note 5)	$C_L$ = 5 pF, $R_L$ = 50 $\Omega$ , Figure 7, Figure 9	3.3	-	0.25	-	ns
t <sub>RF</sub>	Slow Turn-On/Off Switch Paths (Note 5)	$C_L$ = 5 pF, Dn at 0 V or 3.6 V, 40.5 $\Omega$ in series with switch 10% to 90%	3.3	_	4.5	_	ns
t <sub>BBM</sub>	Break-Before-Make Time (Note 5)	$R_L$ = 50 Ω, $C_L$ = 35 pF, V <sub>SW1</sub> = V <sub>SW2</sub> = 0.8 V, Figure 11	2.5 to 4.4	126	-	400	μs
O <sub>IRR</sub>	Off Isolation (Note 5)	$R_L = 50 \Omega$ , f = 240MHz, Figure 13	2.5 to 4.4	-	-40	-	dB
X <sub>talk</sub>	Channel-to-Channel Crosstalk (Note 5)	$R_L$ = 50 $\Omega$ , f = 240MHz, Figure 14	2.5 to 4.4	_	-40	_	dB
t <sub>SK(P)</sub>	Pulse Skew (Note 5)	$V_{SW}$ = 0.2 V diff <sub>PP</sub> , Figure 10, C <sub>L</sub> = 5 pF	2.5 to 4.4	-	25	-	ps
t <sub>SK(I)</sub>	Skew Between Differential Signals Within a Pair (Note 5)	$V_{SW}$ = 0.2 V diff <sub>PP</sub> , Figure 10, C <sub>L</sub> = 5 pF	2.5 to 4.4	-	25	_	ps

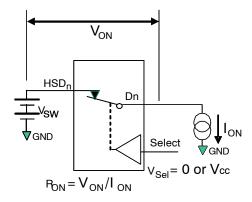
5. Guaranteed by characterization.

CAPACITANCE CHARACTERISTICS	(All typical values are for \	V <sub>CC</sub> = 3.3 V at T <sub>A</sub> = 25°	<sup>o</sup> C unless otherwise specified.)
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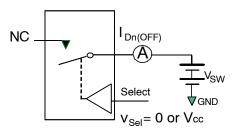
Symbol	Parameter	Test Conditions	V <sub>CC</sub> (V)	Typical	Unit
C <sub>IN</sub>	Input Capacitance (Note 6)		0	3	pF
C <sub>ON</sub>	D+/D- On Capacitance (Note 6)	Any Switch Path Enabled, f = 1MHz, Figure 16	3.3	7.5	
C <sub>OFF</sub>	HSD0n, HSD1n, HSD2n, HSD3n Off Capacitance (Note 6)	If $V_{CC}$ = 3.3 V, then /OE = 3.3 V; f = 1MHz, Figure 15	0 or 3.3	2.2	

6. Guaranteed by characterization.

## **TEST DIAGRAMS**

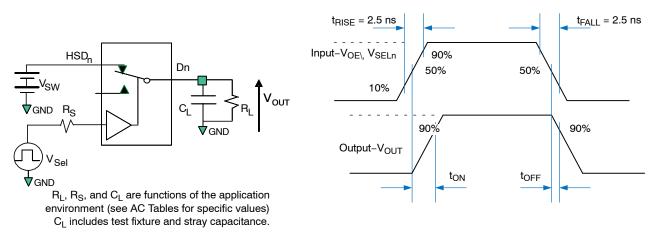




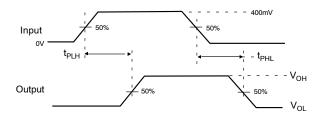


\*\*Eachswitchportistestedseparately

#### Figure 6. Off Leakage

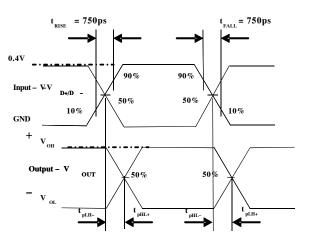


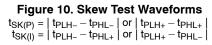




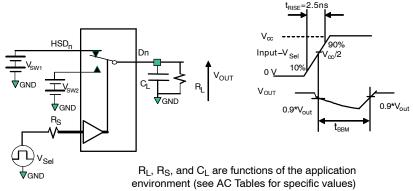




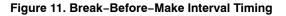


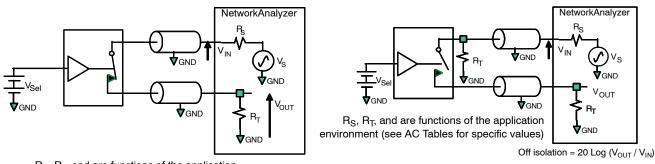


## **TEST DIAGRAMS**



CL includes test fixture and stray capacitance.





 $R_S$ ,  $R_T$ , and are functions of the application environment (see AC Tables for specific values)

#### Figure 12. Bandwidth

#### Figure 13. Channel Off Isolation

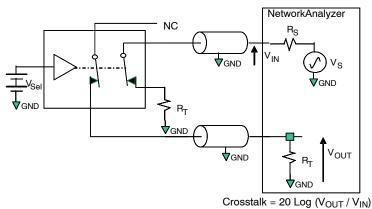


Figure 14. Non-Adjacent Channel-to-Channel Crosstalk

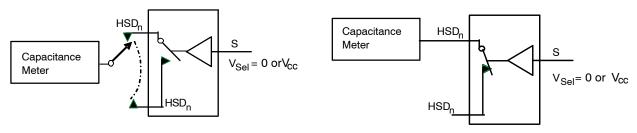


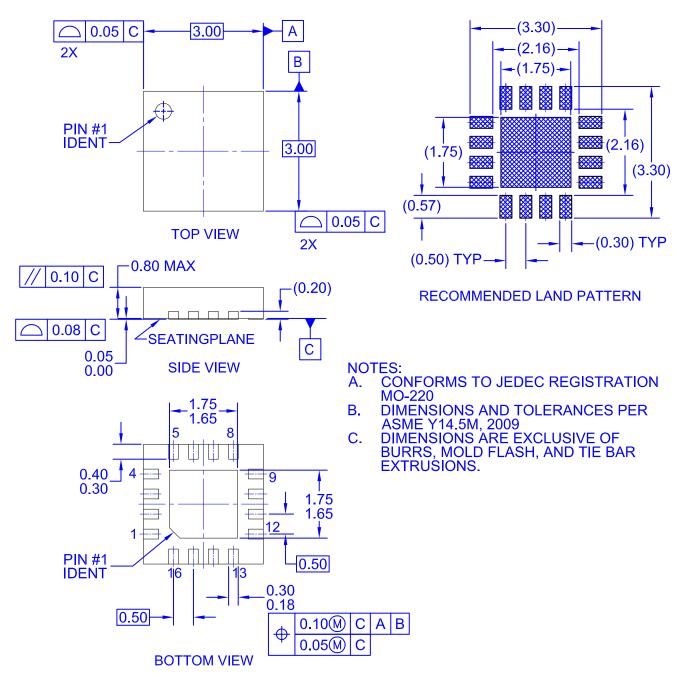


Figure 16. Channel On Capacitance



WQFN16 3x3, 0.5P CASE 510BS ISSUE O

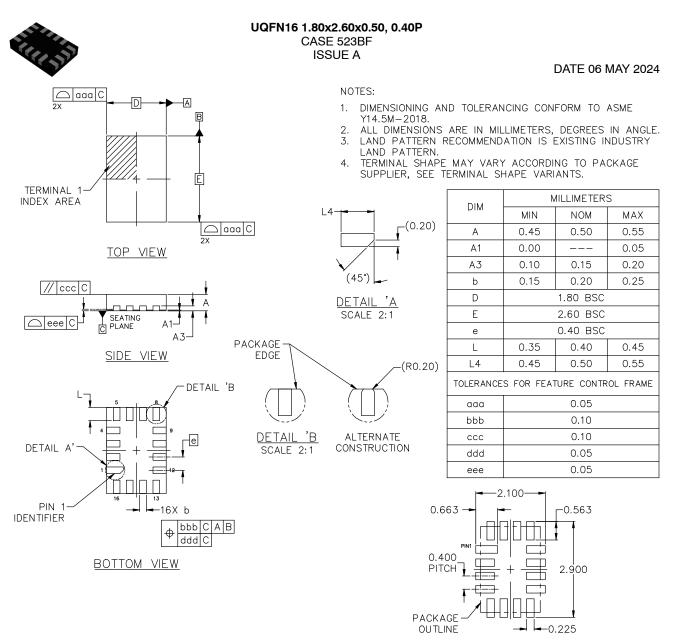
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